

TECHNICAL DATA DATA SHEET 4626, REV.B

HERMETIC POWER SCHOTTKY RECTIFIER

(SINGLE / DUAL)

DESCRIPTION: A 100 VOLT, 30 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC SMD-1 PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE @ $T_C = 25$ °C UNLESS OTHERWISE SPECIFIED.

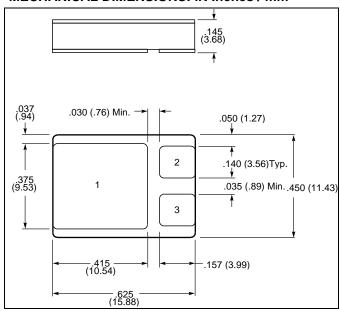
RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	100	Volts
MAXIMUM DC OUTPUT CURRENT With Cathode Maintained (@ T _C =100 °C) (Single)	lo	30	Amps
MAXIMUM DC OUTPUT CURRENT With Cathode Maintained (@ T _C =100 °C) (Common Cathode)	lo	30	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT (t = 8.3ms, Sine)	I _{FSM}	200	Amps
MAXIMUM JUNCTION CAPACITANCE (V _r =5V)	Ст	1200	pF
MAXIMUM THERMAL RESISTANCE PER LEG	R _θ JC	1.8	°C/W
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	Top/Tstg	-65 to + 200	°C

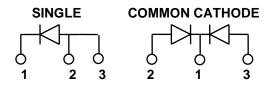
ELECTRICAL CHARACTERISTICS

CHARACTERISTIC			
MAXIMUM FORWARD VOLTAGE DROP, Pulsed (I _f = 30 Amps)			
T _J = 25 °C	V _f	0.93	Volts
T _J = 125 °C		0.77	
MAXIMUM REVERSE CURRENT (Ir @ 100 V PIV)			
T _J = 25 °C	I _r	0.75	mA
T _J = 125 °C		15	

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MECHANICAL DIMENSIONS: IN Inches / mm

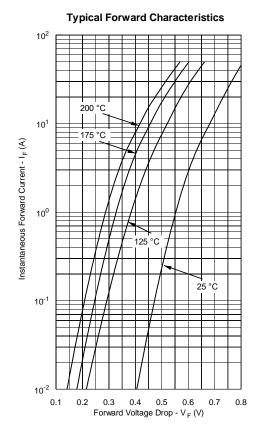


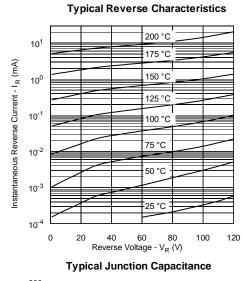


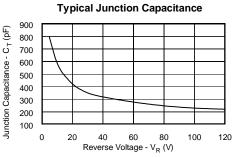
SMD-1

PINOUT TABLE

DEVICE TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
COMMON CATHODE	COMMON CATHODE	ANODE 1	ANODE 2

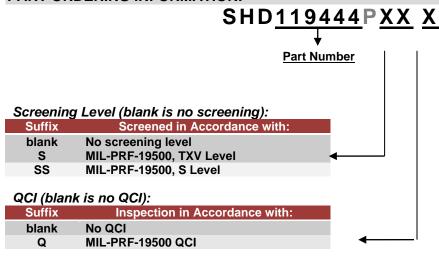






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